



120V NPN MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223

Features

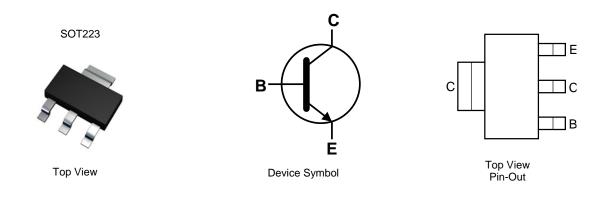
- BV_{CEO} > 120V
- $BV_{CBO} > 120V$
- I_C = 1A Continuous Current
- hFE > 400 for High Gain @ 0.2A
- Very Low Saturation Voltage
- Complementary PNP Type: FZT795A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT223 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020 Terminals: Finish - Matte Tin Plated Leads.
- Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.112 grams (Approximate)

Applications

- **Darlington Replacement**
- Relay and Solenoid Driver



Ordering Information (Notes 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT694BTA	AEC-Q101	FZT694B	7	12	1,000

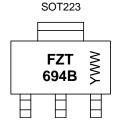
Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



FZT 694B = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	120	V
Collector-Emitter Voltage	V _{CEO}	120	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	Ic	1	A
Peak Pulse Current	I _{CM}	2	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		3.0		
Power Dissipation	(Note 6)	_	2.0	w	
Power Dissipation	(Note 7)	PD	1.6	vv	
	(Note 8)		1.2		
	(Note 5)		41.7		
Thermal Desistance Junction to Ambient	(Note 6)	<u> </u>	62.5		
Thermal Resistance, Junction to Ambient	(Note 7)	R _θ JA	78.1	°C/W	
	(Note 8)		104		
Thermal Resistance Junction to Lead	(Note 9)	R _θ JL	12.9		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 10)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on 50mm x 50mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

6. Same as Note 6, except the device is mounted on 25mm x 25mm 2oz copper.

7. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.

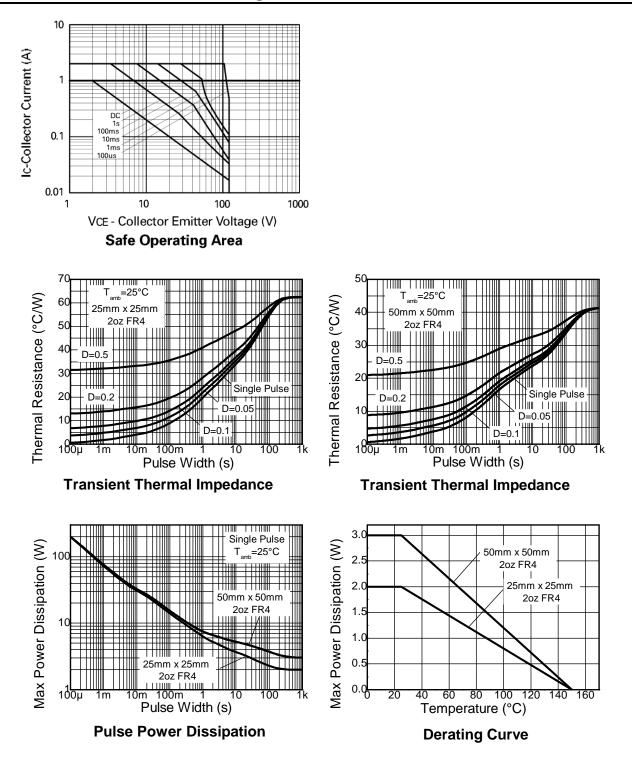
8. Same as Note 6, except the device is mounted on minimum recommended pad layout.

9. Thermal resistance from junction to solder-point (at the end of the collector lead).

10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





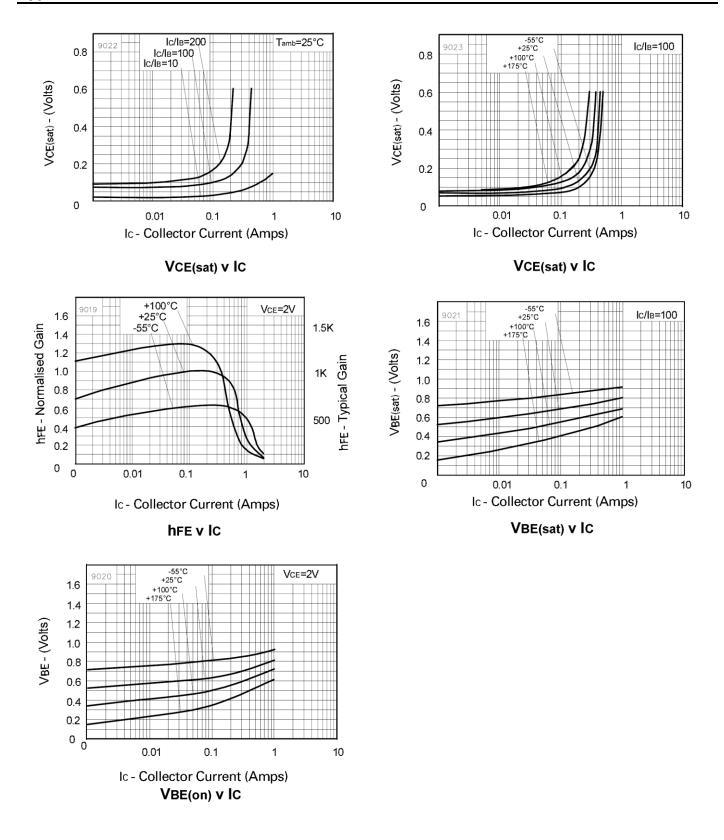
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	120	_	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 11)	BV _{CEO}	120	_	_	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	_	V	I _E = 100μA
Collector-Base Cutoff Current	I _{CBO}	_	_	100	nA	V _{CB} = 100V
Collector-Emitter Cutoff Current	ICES	_	_	100	nA	V _{CE} = 100V
Emitter Cutoff Current	I _{EBO}	—	—	100	nA	$V_{EB} = 6V$
DC Current Gain (Note 11)	h _{FE}	500 400 150			_	$ I_{C} = 100 m A, V_{CE} = 2 V \\ I_{C} = 200 m A, V_{CE} = 2 V \\ I_{C} = 400 m A, V_{CE} = 2 V $
Collector-Emitter Saturation Voltage (Note 11)	V _{CE(sat)}			250 500	mV	$I_{C} = 100mA, I_{B} = 0.5mA$ $I_{C} = 400mA, I_{B} = 5mA$
Base-Emitter Saturation Voltage (Note 11)	V _{BE(sat)}	—	—	0.9	V	$I_{\rm C} = 1$ A, $I_{\rm B} = 10$ mA
Base-Emitter Turn-On Voltage (Note 11)	V _{BE(on)}	_	_	0.9	V	$I_{C} = 1A, V_{CE} = 2V$
Input Capacitance	C _{ibo}	_	200	_	pF	V _{EB} = 0.5V, f = 1MHz
Output Capacitance	Cobo	_	9	_	pF	$V_{CB} = 10V$, f = 1MHz
Current Gain-Bandwidth Product	fT	130	_	_	MHz	$V_{CE} = 5V, I_C = 50mA, f=50MHz$
Turn-On Time	t _{on}	—	80	—	ns	$V_{CC} = 50V, I_C = 100mA$
Turn-Off Time	t _{off}	—	2,900	—	ns	$I_{B1} = -I_{B2} = 10 \text{mA}$

Note: 11. Measured under pulsed conditions. Pulse width \leq 300 µs. Duty cycle \leq 2%.



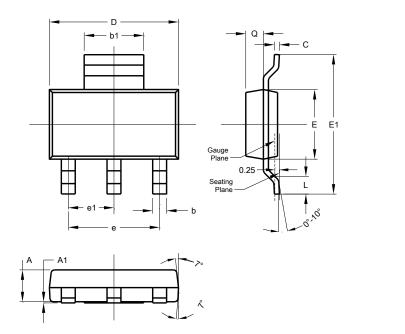
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

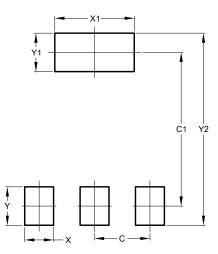
Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.



SOT223				
Dim	Min	Max	Тур	
Α	1.55	1.65	1.60	
A1	0.010	0.15	0.05	
b	0.60	0.80	0.70	
b1	2.90	3.10	3.00	
С	0.20	0.30	0.25	
D	6.45	6.55	6.50	
E	3.45	3.55	3.50	
E1	6.90	7.10	7.00	
е	-	-	4.60	
e1	-	-	2.30	
L	0.85	1.05	0.95	
Q	0.84	0.94	0.89	
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00



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